ne<mark>x</mark>peria

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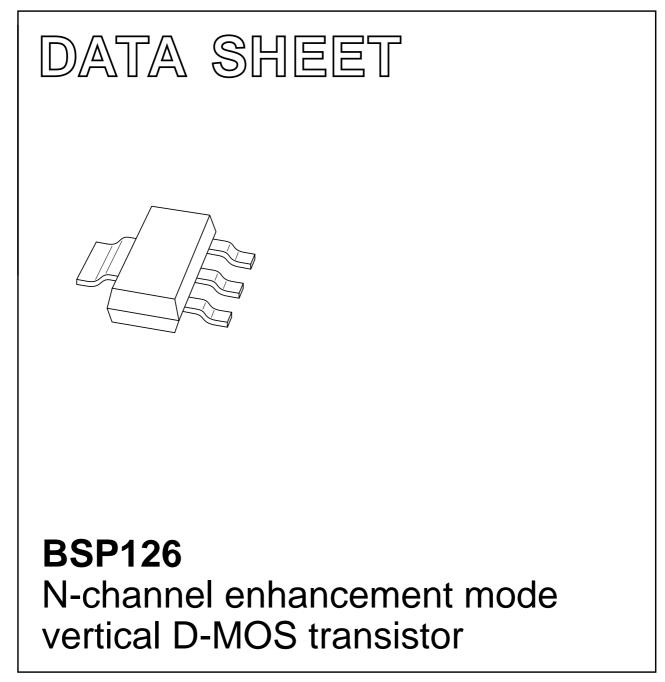
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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1997 Jun 23 2002 Feb 19





HILIP

FEATURES

- Direct interface to C-MOS, TTL, etc.
- High-speed switching
- No secondary breakdown.

APPLICATIONS

- Line current interruptor in telephone sets
- Relay, high-speed and line transformer drivers.

DESCRIPTION

N-channel enhancement mode vertical D-MOS transistor in a miniature SOT223 package.

MARKING

TYPE NUMBER	MARKING CODE			
BSP126	BSP126			

QUICK REFERENCE DATA

SYMBOL	L PARAMETER CONDITIONS T		TYP.	MAX.	UNIT
V _{DS}	drain-source voltage (DC)		-	250	V
I _D	drain current (DC)		_	375	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	-	1.5	W
R _{DSon}	drain-source on-state resistance	$I_D = 300 \text{ mA}; V_{GS} = 10 \text{ V}$	2.8	5	Ω
V _{GSth}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}$	_	2	V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	drain-source voltage (DC)		-	250	V
V _{GSO}	gate-source voltage (DC)	open drain	-	±20	V
I _D	drain current (DC)		_	375	mA
I _{DM}	peak drain current		-	1.3	A
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$; note 1	-	1.5	W
T _{stg}	storage temperature		-55	+150	°C
Tj	junction temperature		-	150	°C

Note

1. Device mounted on a $40 \times 40 \times 1.5$ mm epoxy printed-circuit board; mounting pad for the drain tab minimum 6 cm².

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PINNING - SOT223			
PIN	DESCRIPTION		
1	gate		
2	drain		
3	source		
4	drain		

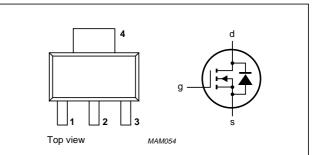


Fig.1 Simplified outline and symbol.

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient; note 1	83.3	K/W

Note

1. Device mounted on a $40 \times 40 \times 1.5$ mm epoxy printed-circuit board; mounting pad for the drain tab minimum 6 cm².

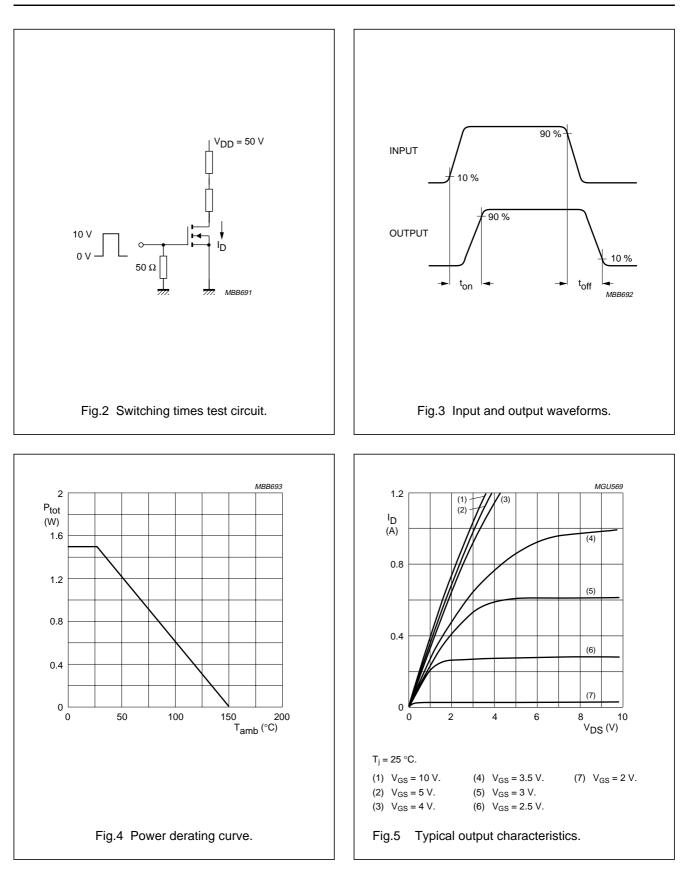
CHARACTERISTICS

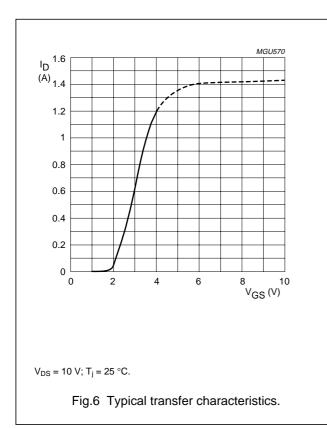
 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

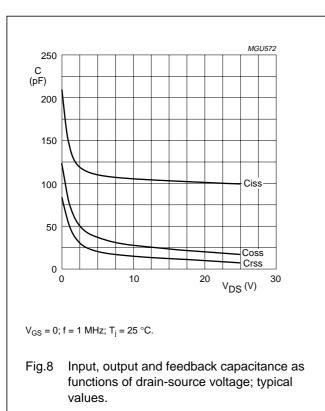
SYMBOL	PARAMETER	PARAMETER CONDITIONS		TYP.	MAX.	UNIT
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = 10 \ \mu A; \ V_{GS} = 0$	250	-	-	V
I _{GSS}	gate-source leakage current	$V_{GS} = \pm 20 \text{ V}; V_{DS} = 0$	_	_	±100	nA
V _{GSth}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}$	0.8	_	2	V
R _{DSon}	drain-source on-state resistance	I _D = 20 mA; V _{GS} = 2.4 V	-	_	7.5	Ω
		$I_D = 300 \text{ mA}; V_{GS} = 10 \text{ V}$	-	2.8	5	Ω
I _{DSS}	drain-source leakage current	$V_{DS} = 200 \text{ V}; \text{ V}_{GS} = 0$	_	_	1	μA
Y _{fs}	transfer admittance	I _D = 300 mA; V _{DS} = 25 V	200	600	_	mS
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0; f = 1 MHz	_	100	120	pF
C _{oss}	output capacitance	V _{DS} = 25 V; V _{GS} = 0; f = 1 MHz	_	21	30	pF
C _{rss}	feedback capacitance	V _{DS} = 25 V; V _{GS} = 0; f = 1 MHz	_	10	15	pF
Switching tin	mes (see Figs 2 and 3)		•			
t _{on}	turn-on time	$I_D = 250 \text{ mA}; V_{DD} = 50 \text{ V};$ $V_{GS} = 0 \text{ to } 10 \text{ V}$	-	6	10	ns
t _{off}	turn-off time	$I_D = 250 \text{ mA}; V_{DD} = 50 \text{ V};$ $V_{GS} = 10 \text{ to } 0 \text{ V}$	-	47	60	ns

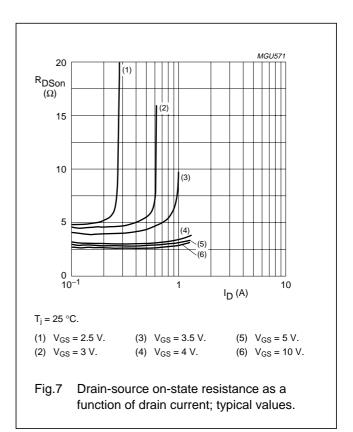
BSP126

N-channel enhancement mode vertical D-MOS transistor





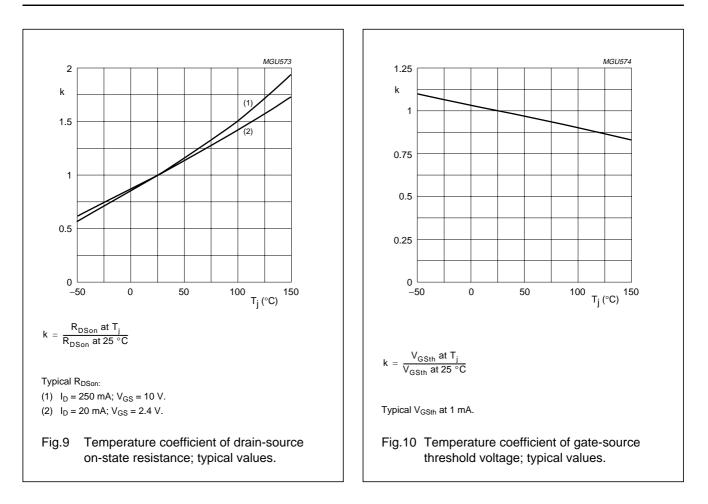




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N-channel enhancement mode vertical D-MOS transistor

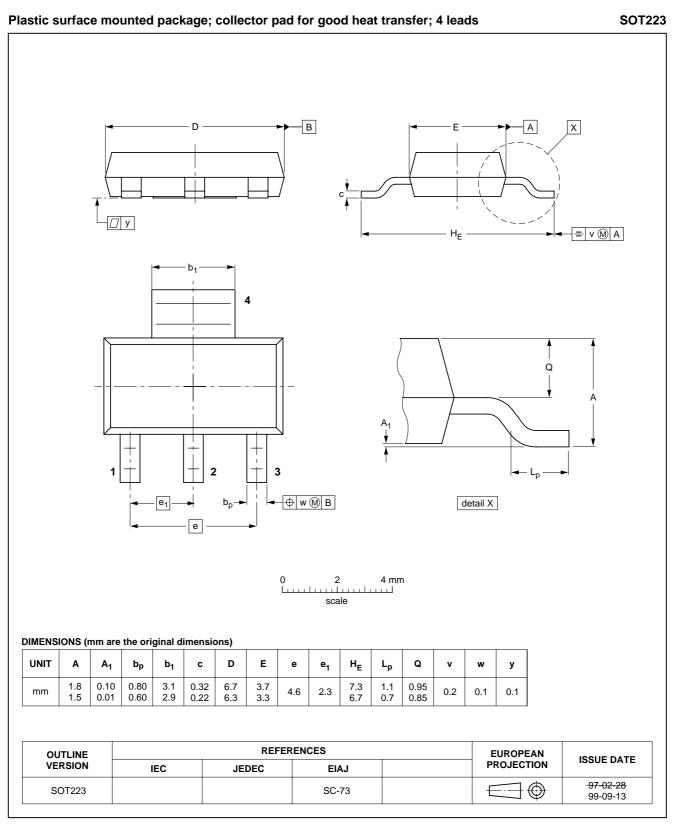


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N-channel enhancement mode vertical D-MOS transistor

PACKAGE OUTLINE



BSP126

DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Contact information

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